

**100V NPN DARLINGTON TRANSISTOR IN SOT223**

**Features**

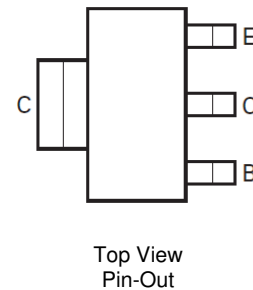
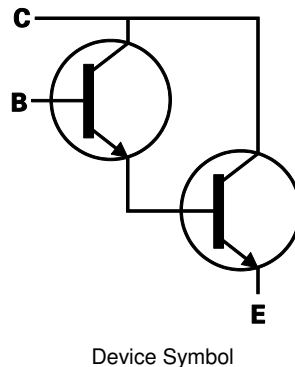
- $BV_{CEO} > 100V$
- $BV_{CBO} > 100V$
- $I_C = 1.5A$  High Continuous Current
- $hFE > 10k$  for very High Gain @100mA
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

**Mechanical Data**

- Case: SOT223
- Case material: Molded Plastic. "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.112 grams (Approximate)

**Applications**

- Lamp
- Relay
- Solenoid Driving

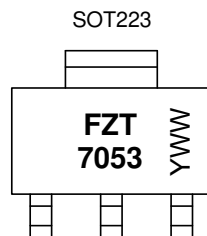


**Ordering Information** (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FZT7053TA	FZT7053	7	12	1,000

- Notes:
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
  2. See [http://www.diodes.com/quality/lead\\_free.html](http://www.diodes.com/quality/lead_free.html) for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

**Marking Information**



FZT 7053 = Product Type Marking Code  
 YWW = Date Code Marking  
 Y or  $\bar{Y}$  = Last Digit of Year (ex: 5= 2015)  
 WW or  $\bar{W}W$  = Week Code (01~53)

### Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

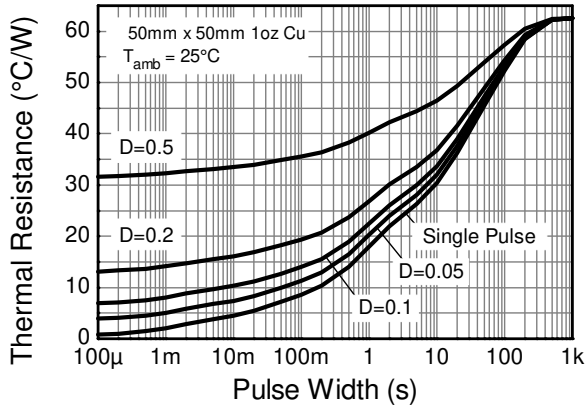
Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CB0</sub>	100	V
Collector-Emitter Voltage	V <sub>CEO</sub>	100	V
Emitter-Base Voltage	V <sub>EBO</sub>	12	V
Continuous Collector Current	I <sub>C</sub>	1.5	A
Peak Pulse Current	I <sub>CM</sub>	2	A

### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

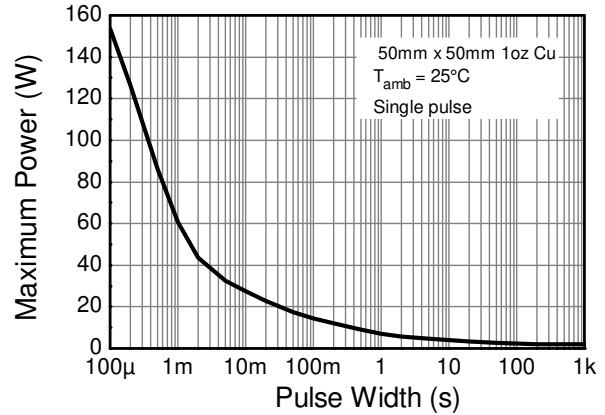
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P <sub>D</sub>	1	W
Power Dissipation (Note 6)	P <sub>D</sub>	1.25	W
Power Dissipation (Note 7)	P <sub>D</sub>	2	W
Thermal Resistance, Junction to Ambient (Note 5)	R <sub>θJA</sub>	125	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	R <sub>θJA</sub>	100	°C/W
Thermal Resistance, Junction to Ambient (Note 7)	R <sub>θJA</sub>	62	°C/W
Thermal Resistance, Junction to Lead (Note 8)	R <sub>θJL</sub>	19.4	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

- Notes:
5. For a device surface mounted on 15mm x 14mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
  6. Same as Note 5, except the device is surface mounted on 25mm x 25mm with 1oz copper.
  7. Same as Note 5, except the device is surface mounted on 50mm x 50mm with 1oz copper.
  8. Thermal resistance from junction to solder-point (at the end of the collector lead).

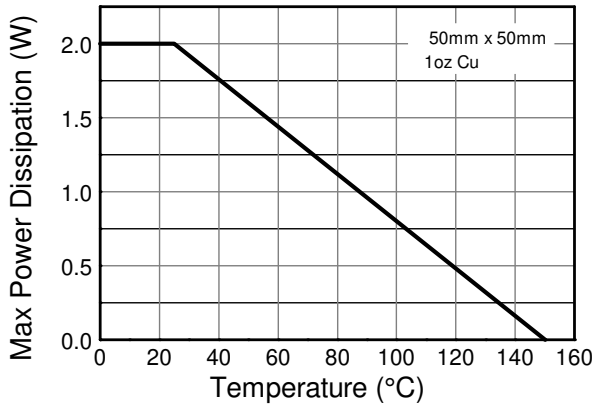
**Thermal Characteristics and Derating Information**



**Transient Thermal Impedance**



**Pulse Power Dissipation**



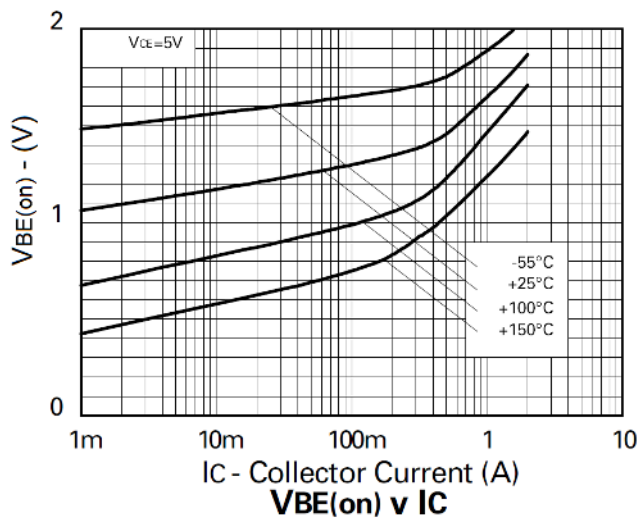
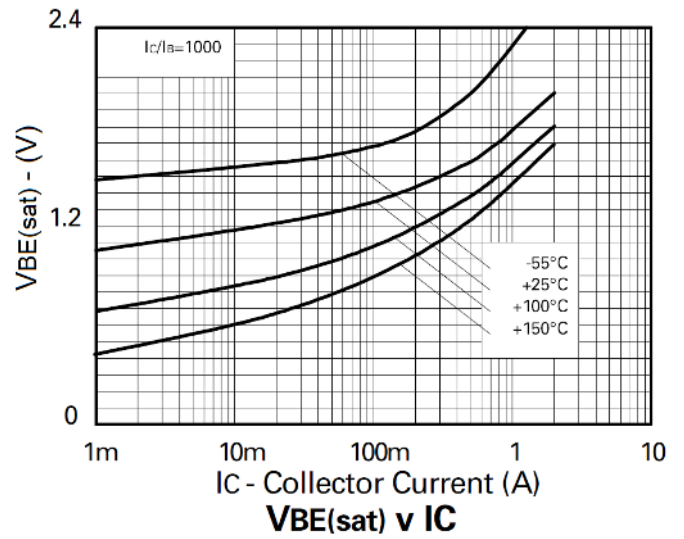
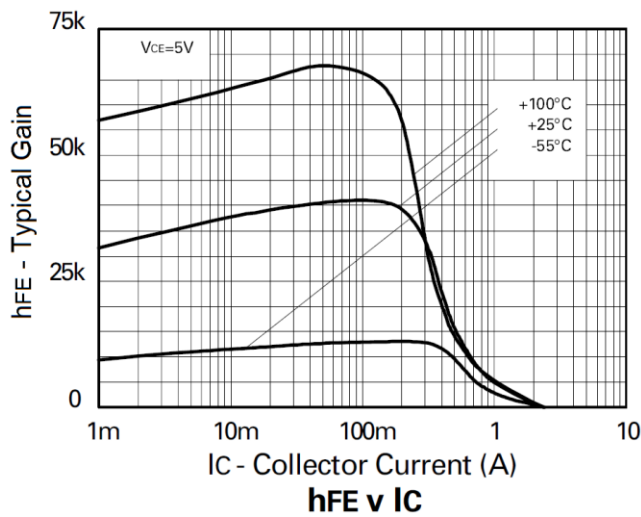
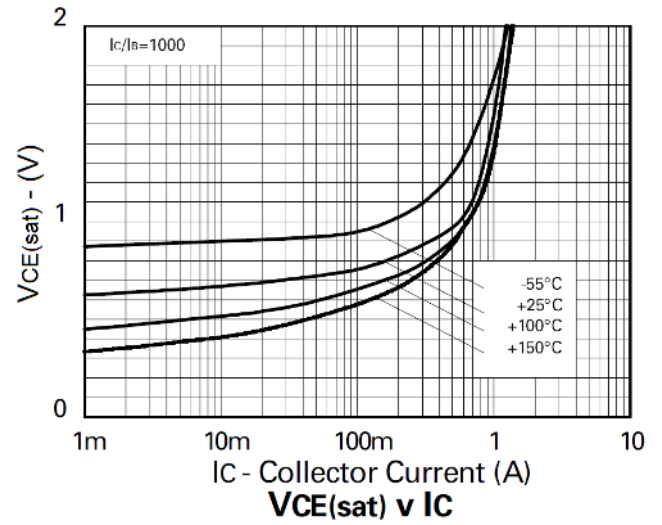
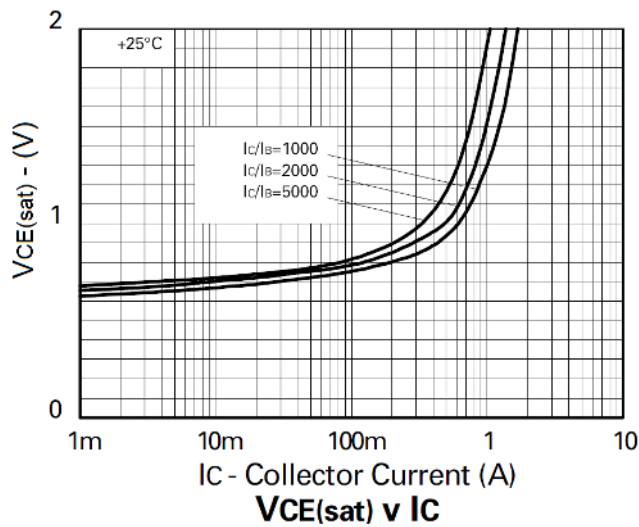
**Derating Curve**

**Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	100	300	-	V	I <sub>C</sub> = 100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	100	130	-	V	I <sub>C</sub> = 1mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	12	14	-	V	I <sub>E</sub> = 100μA
Collector-Base Cut-Off Current	I <sub>CBO</sub>	-	<10	100	nA	V <sub>CB</sub> = 80V
Collector-Emitter Cut-Off Current	I <sub>CES</sub>	-	<10	200	nA	V <sub>CE</sub> = 80V
Emitter Cut-Off Current	I <sub>EBO</sub>	-	<10	100	nA	V <sub>EB</sub> = 7V
DC Current Gain (Note 9)	h <sub>FE</sub>	10,000 1,000	-	-	-	I <sub>C</sub> = 100mA, V <sub>CE</sub> = 5V I <sub>C</sub> = 1A, V <sub>CE</sub> = 5V
Collector-Emitter Saturation Voltage (Note 9)	V <sub>CE(sat)</sub>	-	-	1.5	V	I <sub>C</sub> = 100mA, I <sub>B</sub> = 0.1mA
Base-Emitter Turn-On Voltage (Note 9)	V <sub>BE(on)</sub>	-	-	2.0	V	I <sub>C</sub> = 100mA, V <sub>CE</sub> = 5V
Output Capacitance (Note 9)	C <sub>obo</sub>	-	6.0	8.0	pF	V <sub>CB</sub> = 10V, f = 1MHz
Current Gain-Bandwidth Product (Note 9)	f <sub>T</sub>	200	-	-	MHz	V <sub>CE</sub> = 5V, I <sub>C</sub> = 100mA
Turn-On Time	t <sub>on</sub>	-	0.7	-	μs	V <sub>CC</sub> = 10V, I <sub>C</sub> = 100μA
Turn-Off Time	t <sub>off</sub>	-	2.5	-	μs	I <sub>B1</sub> = -I <sub>B2</sub> = 0.1mA

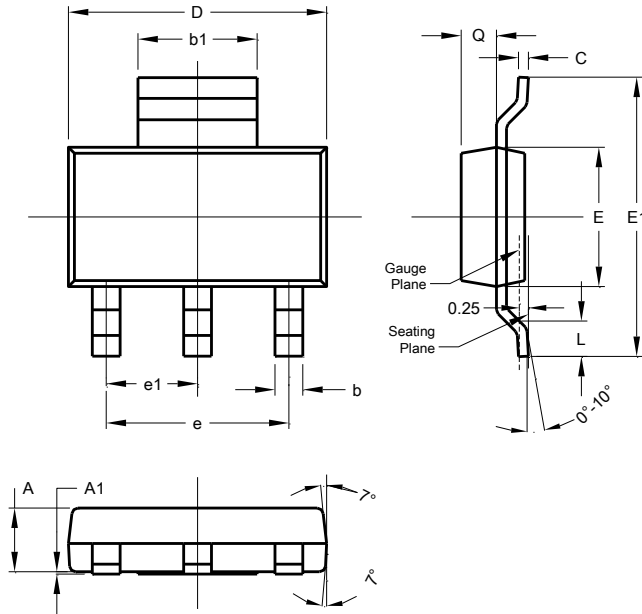
Note: 9. Measured under pulsed conditions. Pulse width ≤ 300 μs. Duty cycle ≤ 2%.

**Typical Electrical Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)



## Package Outline Dimensions

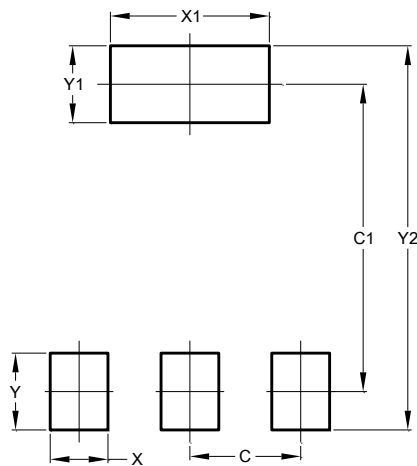
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.



SOT223			
Dim	Min	Max	Typ
A	1.55	1.65	1.60
A1	0.010	0.15	0.05
b	0.60	0.80	0.70
b1	2.90	3.10	3.00
C	0.20	0.30	0.25
D	6.45	6.55	6.50
E	3.45	3.55	3.50
E1	6.90	7.10	7.00
e	-	-	4.60
e1	-	-	2.30
L	0.85	1.05	0.95
Q	0.84	0.94	0.89
All Dimensions in mm			

## Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
C	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
C2	8.00

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